

TOSHIBA BIPOLAR LINEAR INTEGRATED CIRCUIT SILICON MONOLITHIC

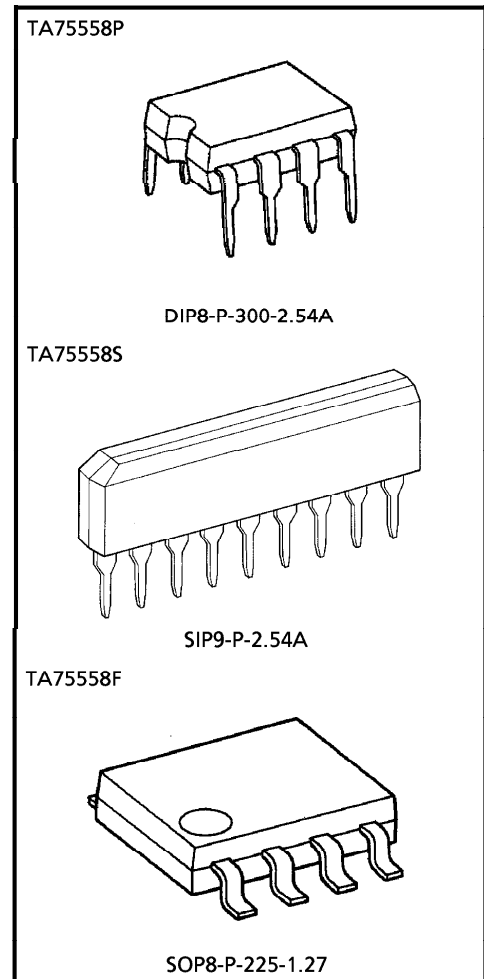
TA75558P, TA75558S, TA75558F

DUAL OPERATIONAL AMPLIFIER

The TA75558P, TA75558S and TA75558F are Low-Noise Operational Amplifiers with High Speed and Wide Bandwidth.

FEATURES

- Internal Frequency Compensation Type
- Pin Compatible with TA75458P, TA75458S and TA75458F
- Possible to Exchange the Position of 9 Pin for 1 Pin Because of Pin Connection Being Symmetric.
(TA75558S Device Only)
- Wide Band Range : $f_T = 3\text{MHz}$ (Typ.)
- Suitable Application for Active Filter Equalizer Amplifier and Headphone Amplifier.



Weight

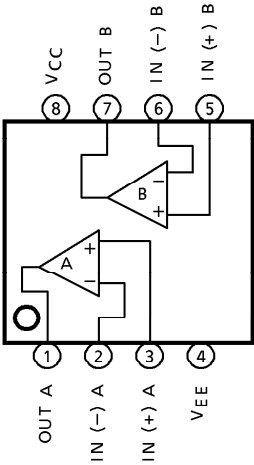
DIP8-P-300-2.54A	: 0.5g (Typ.)
SIP9-P-2.54A	: 0.9g (Typ.)
SOP8-P-225-1.27	: 0.1g (Typ.)

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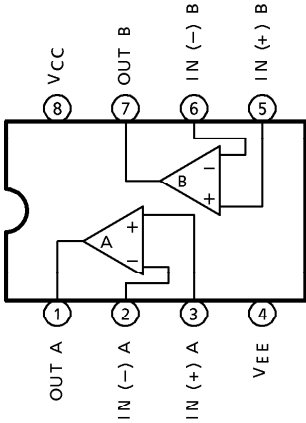
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PIN CONNECTION (TOP VIEW)

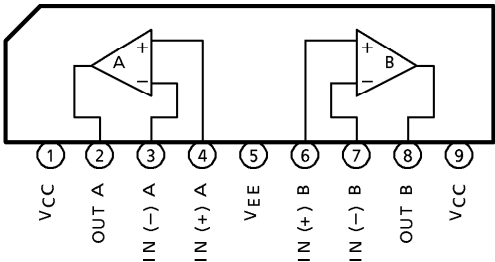
TA75558F



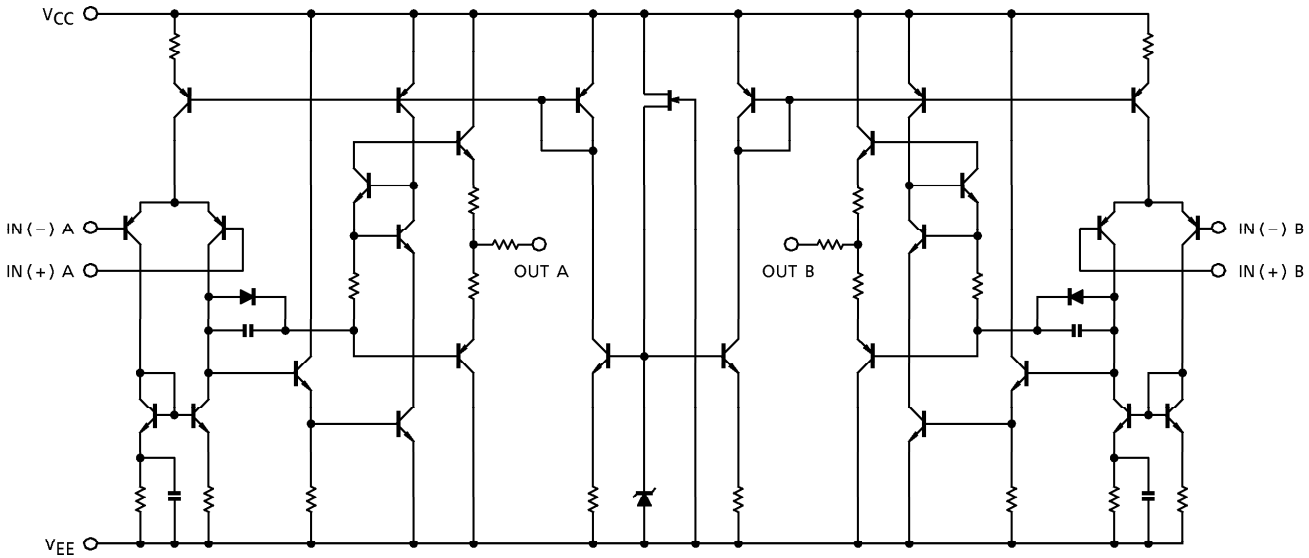
TA75558P



TA75558S



EQUIVALENT CIRCUIT



MAXIMUM RATINGS ($T_a = 25^\circ\text{C}$)

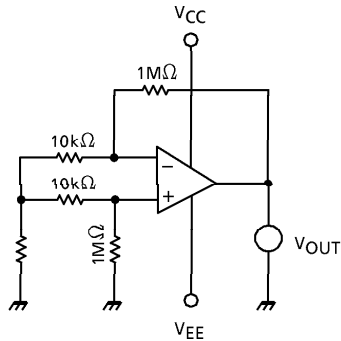
CHARACTERISTIC	SYMBOL	TA75558P TA75558S	TA75558F	UNIT
Supply Voltage	V_{CC}	+ 18	+ 18	V
	V_{EE}	- 18	- 18	
Differential Input Voltage	DV_{IN}	± 30	± 30	V
Input Voltage	V_{IN}	$V_{CC} \sim V_{EE}$	$V_{CC} \sim V_{EE}$	V
Power Dissipation	P_D	500	240	mW
Operating Temperature	T_{opr}	- 40~85	- 30~70	$^\circ\text{C}$
Storage Temperature	T_{stg}	- 55~125	- 55~125	$^\circ\text{C}$

ELECTRICAL CHARACTERISTICS ($V_{CC} = 15\text{V}$, $V_{EE} = -15\text{V}$, $T_a = 25^\circ\text{C}$)

CHARACTERISTIC	SYMBOL	TEST CIR- CUIT	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Input Offset Voltage	V_{IO}	1	$R_g \leq 10\text{k}\Omega$	—	0.5	6	mV
Input Offset Current	I_{IO}	2	—	—	5	200	nA
Input Bias Current	I_I	2	—	—	60	500	nA
Common Mode Input Voltage	CMV_{IN}	3	—	± 12	± 14	—	V
Maximum Output Voltage	V_{OM}	6	$R_L = 10\text{k}\Omega$	± 12	± 14	—	V
	V_{OMR}		$R_L = 2\text{k}\Omega$	± 10	± 13	—	
Source Current	I_{source}	8	—	—	40	—	mA
Sink Current	I_{sink}	7	—	—	40	—	mA
Voltage Gain (Open Loop)	G_V	5	$V_{OUT} = \pm 10\text{V}$, $R_L = 2\text{k}\Omega$	86	100	—	dB
Common Mode Input Signal Rejection Ratio	CMRR	3	$R_g \leq 10\text{k}\Omega$	70	90	—	dB
Supply Voltage Rejection Ratio	SVRR	1	$R_g \leq 10\text{k}\Omega$	—	30	150	$\mu\text{V/V}$
Slew Rate	SR	9	$G_V = 1$, $R_L = 2\text{k}\Omega$	—	1.0	—	$\text{V}/\mu\text{s}$
Unity Gain Cross Frequency	f_T	5	Open Loop	—	3.0	—	MHz
Supply Current	I_{CC} , I_{EE}	4	—	—	4.0	6.0	mA
Equivalent Input Noise Voltage	V_{NI}	—	$R_S = 1\text{k}\Omega$, $f = 30\text{Hz} \sim 30\text{kHz}$	—	2.5	—	μV_{rms}

TEST CIRCUIT

(1) V_{IO} , $SVRR$



- $V_{IO} = V_{OUT} / 100$

- $SVRR = 20 \log E \text{ (dB)}$

$$E = \left| \frac{V_{OUT1} - V_{OUT2}}{(V_{CC1} - V_{EE1}) - (V_{CC2} - V_{EE2})} \right| \times \frac{1}{100}$$

V_{OUT1} : V_{OUT} (V_{CC} , $V_{EE} = \pm 8V$)

V_{OUT2} : V_{OUT} (V_{CC} , $V_{EE} = \pm 18V$)

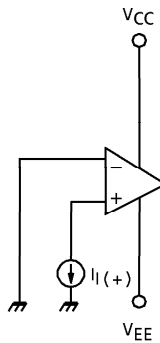
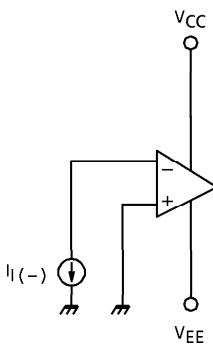
V_{CC1} : $V_{CC} = -8V$

V_{EE1} : $V_{EE} = -8V$

V_{CC2} : $V_{CC} = +18V$

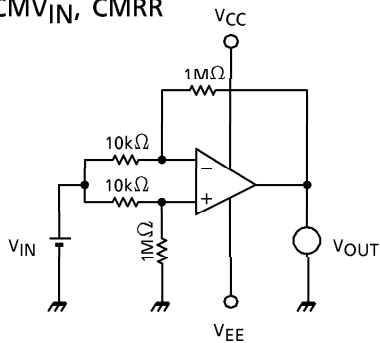
V_{EE2} : $V_{EE} = -18V$

(2) I_I , I_{IO}



$$I_{IO} = |I_I(-) - I_I(+)|$$

(3) CMV_{IN} , $CMRR$



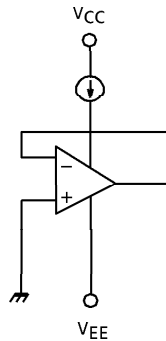
- $CMRR = 20 \log G_D / G_C \text{ (dB)}$

G_D : DIFFERENTIAL VOLTAGE GAIN

G_C : COMMON MODE VOLTAGE GAIN

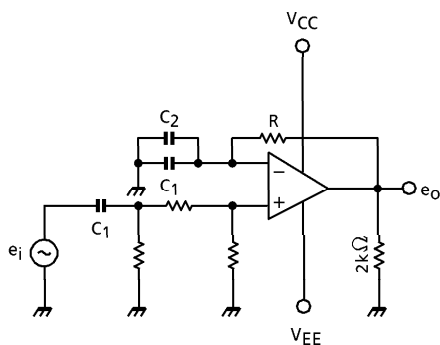
- CMV_{IN} : $V_{IN} = -12V, 12V$ SUPPLIES

(4) I_{CC}



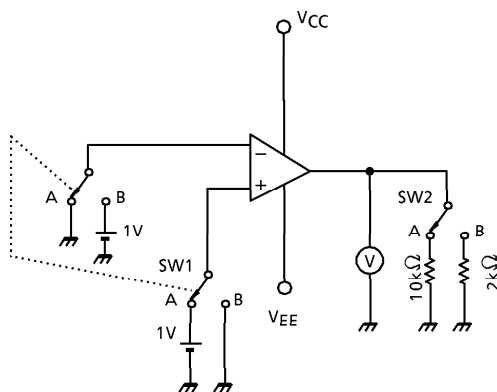
- I_{CC} : V_{CC} , $V_{EE} = \pm 15V$

(5) G_V , f_T



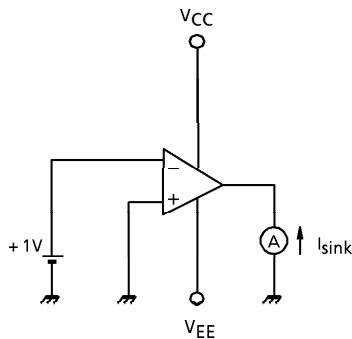
- $G_V = 20 \log e_o / e_i$ (dB)
 $R \gg 1 / \omega C_1$
 C_1 : COUPLING CONDENSER
 C_2 : HIGH FREQUENCY BYPASS CONDENSER
- f_T : INPUT FREQUENCY AT $e_i = e_o$

(6) V_{OM} , V_{OMR}

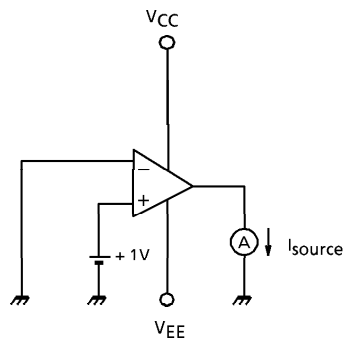


- V_{OM} : (+) : SW1 IS SIDE A, SW2 IS SIDE A
 (-) : SW1 IS SIDE B, SW2 IS SIDE A
- V_{OMR} : (+) : SW1 IS SIDE A, SW2 IS SIDE B
 (-) : SW1 IS SIDE B, SW2 IS SIDE B

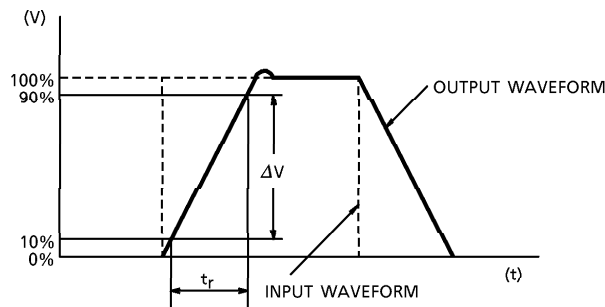
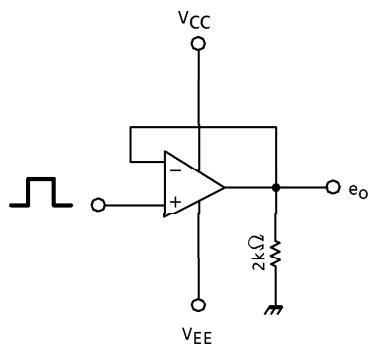
(7) I_{sink}



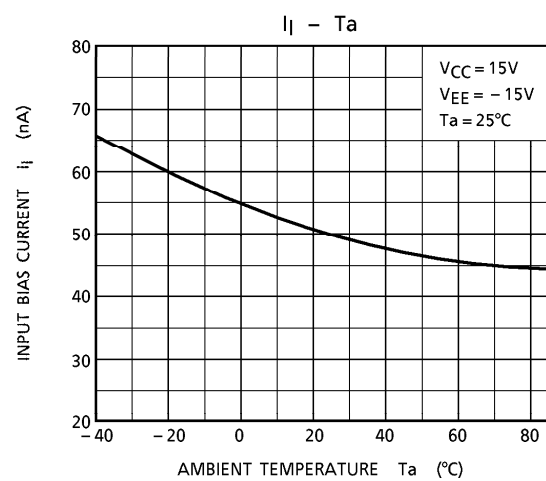
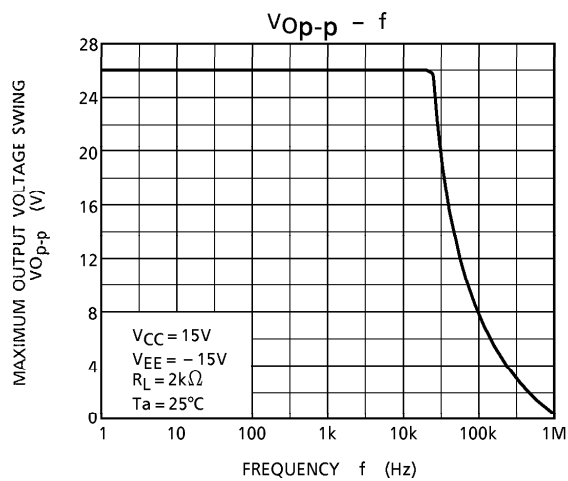
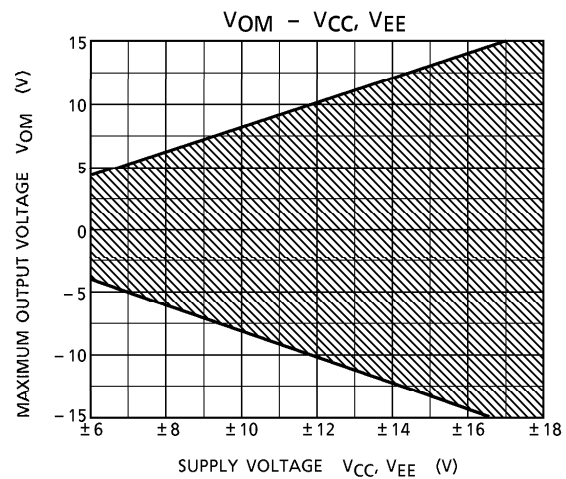
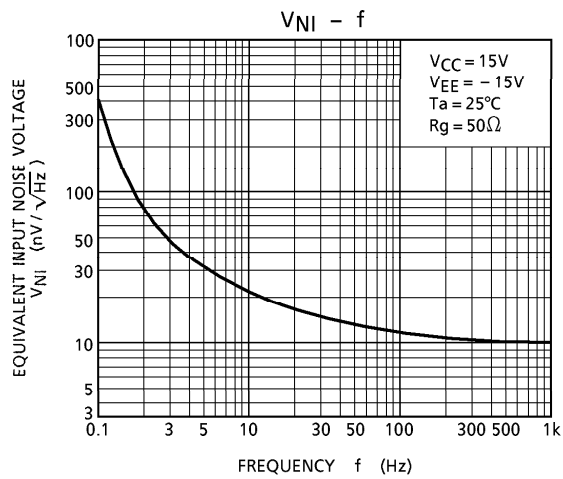
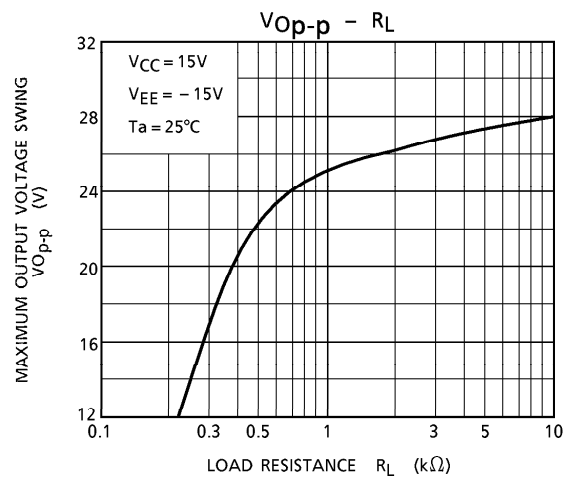
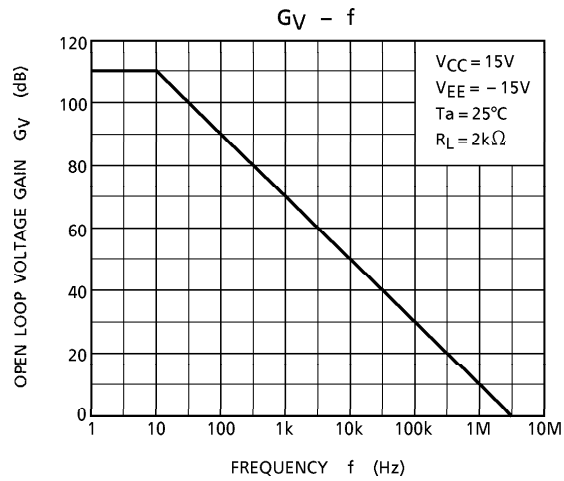
(8) I_{source}

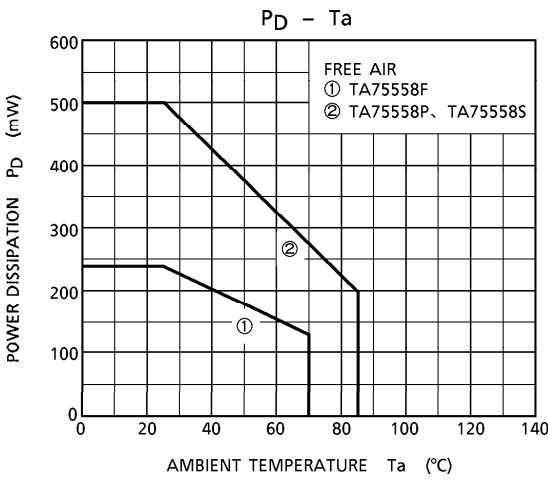


(9) SR



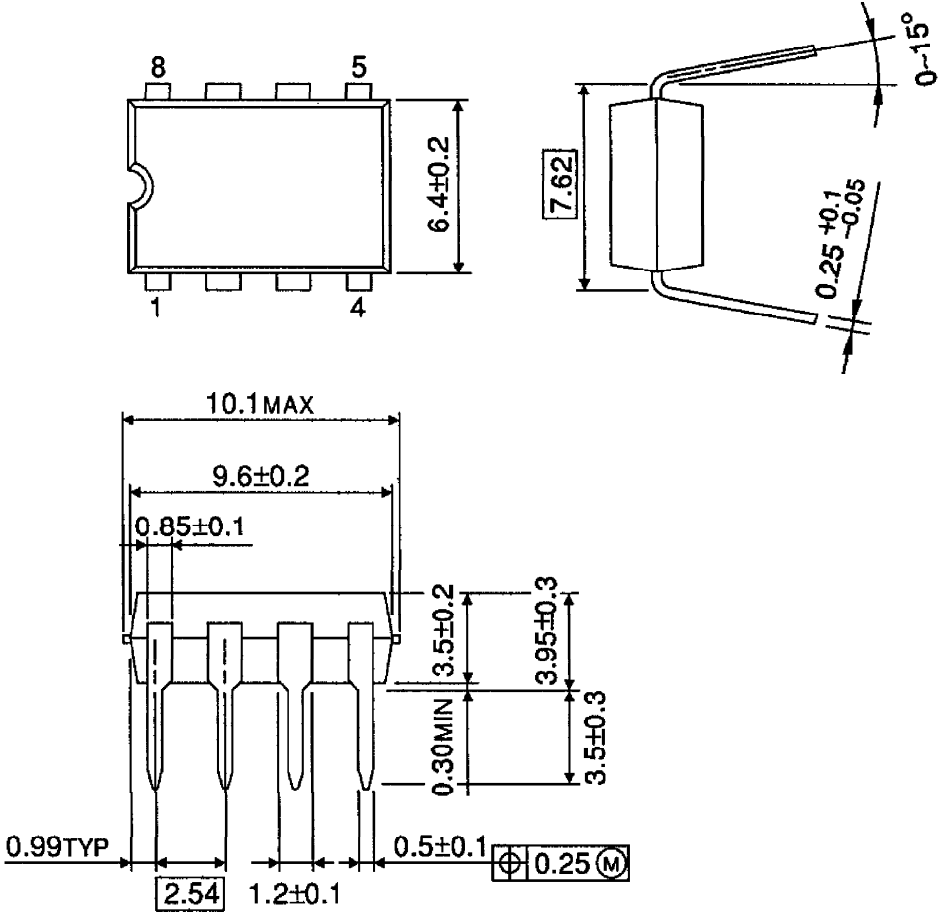
CHARACTERISTIC





OUTLINE DRAWING
DIP8-P-300-2.54A

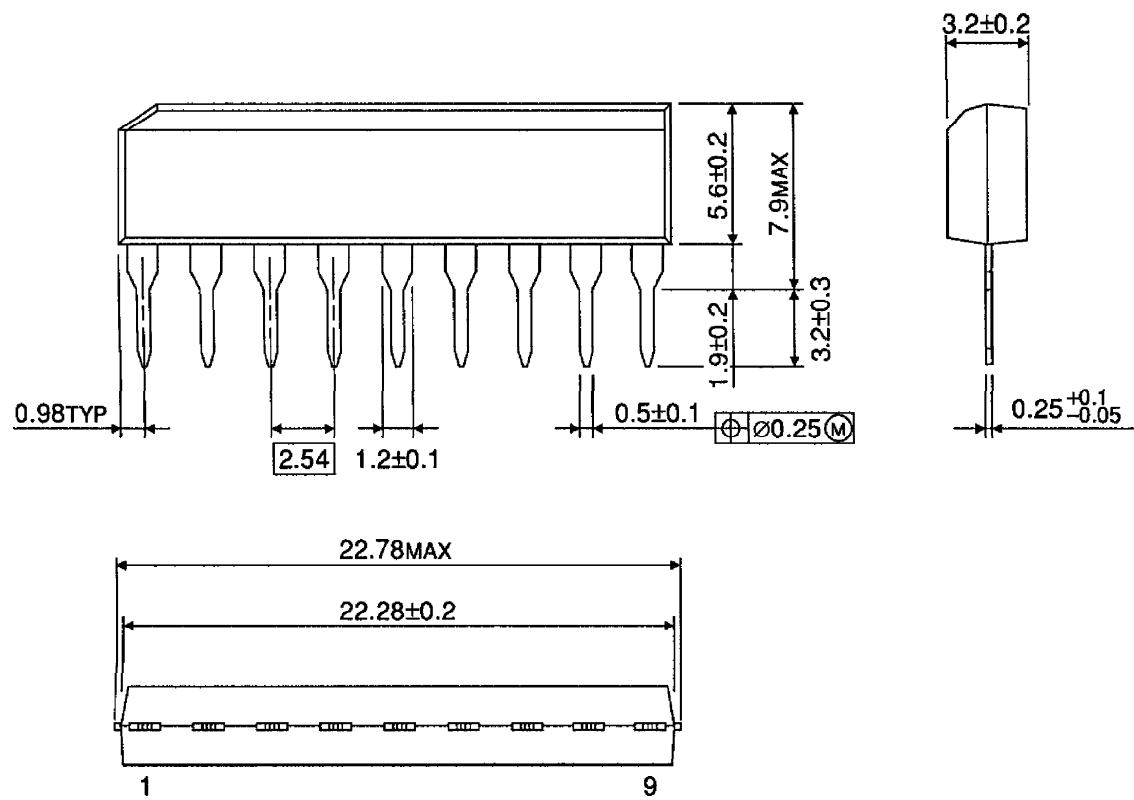
Unit : mm



Weight : 0.5g (Typ.)

OUTLINE DRAWING
SIP9-P-2.54A

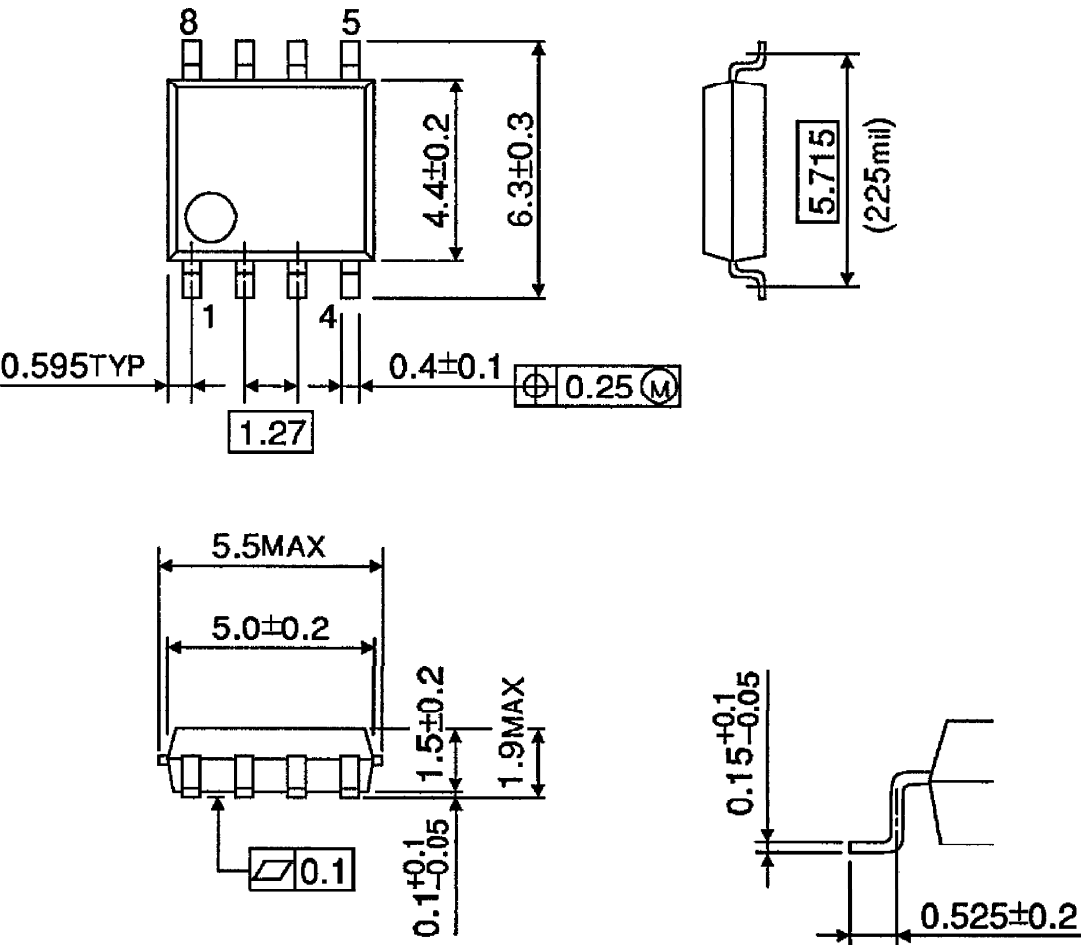
Unit : mm



Weight : 0.9g (Typ.)

OUTLINE DRAWING
SOP8-P-225-1.27

Unit : mm



Weight : 0.1g (Typ.)